

# Silicon Dual NPN Transistor

## **MD708F**

High Speed Transistor

40V / 200mA

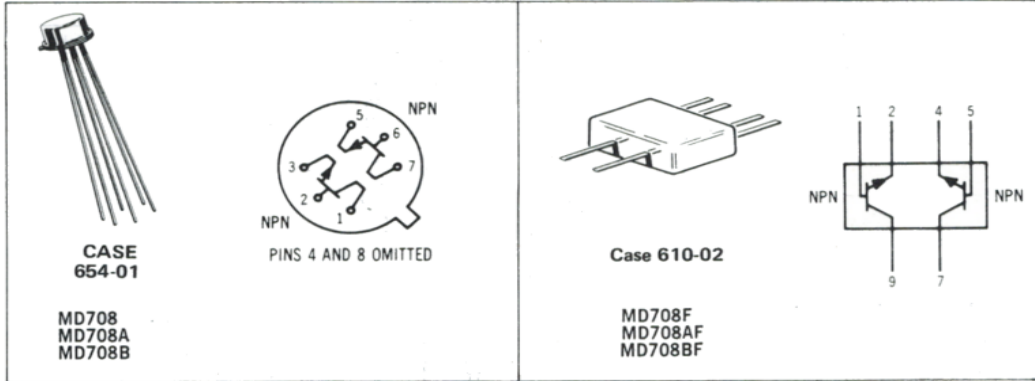
# DATASHEET

OEM –Motorola

Source: Motorola Databook 1972

# MD708, F (SILICON) MD708A, F MD708B, F

Dual NPN silicon annular transistors designed for high-speed, logic switching and space saving considerations. Matched pairs are available for differential amplifier applications.



Pin Connections, Bottom View  
All Leads Electrically Isolated from Case

## MAXIMUM RATINGS (each side) ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

| Rating  | Symbol         | Value   | Unit              |            |                            |
|---|----------------|---|-------------------|------------|----------------------------|
| Collector-Emitter Voltage                           | $V_{CEO}$      | 15  | Vdc               |            |                            |
| Collector-Base Voltage                              | $V_{CB}$       | 40  | Vdc               |            |                            |
| Emitter-Base Voltage                                | $V_{EB}$       | 5.0   | Vdc               |            |                            |
| Collector Current                                   | $I_C$          | 200   | mAdc              |            |                            |
| Operating and Storage Junction Temperature Range    | $T_J, T_{stg}$ | -65 to +200                                     | $^\circ\text{C}$  |            |                            |
| Total Device Dissipation @ $T_A = 25^\circ\text{C}$ | $P_D$          | <b>One Side</b>                                 | <b>Both Sides</b> |            |                            |
|   |                | Metal Can<br>Derate above $25^\circ\text{C}$    | 300<br>1.7        | 400<br>2.3 | mW<br>mW/ $^\circ\text{C}$ |
|   |                | Flat Package<br>Derate above $25^\circ\text{C}$ | 250<br>1.5        | 350<br>2.0 | mW<br>mW/ $^\circ\text{C}$ |
|   |                |   |                   |            |                            |

FIGURE 1 — TURN-ON AND TURN-OFF TIME TEST CIRCUIT

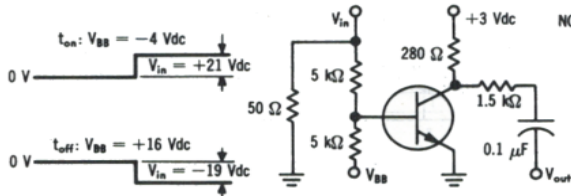
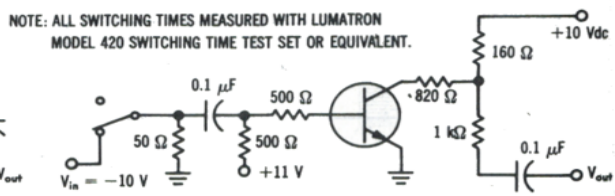


FIGURE 2 — CHARGE-STORAGE TIME CONSTANT TEST CIRCUIT



NOTE: ALL SWITCHING TIMES MEASURED WITH LUMATRON MODEL 420 SWITCHING TIME TEST SET OR EQUIVALENT.

**MD708,F/MD708A,F/MD708B,F** (continued)**ELECTRICAL CHARACTERISTICS** (each side) ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

| Characteristic   | Symbol   | Min                  | Max                 | Unit                         |
|--|--|----------------------|---------------------|------------------------------|
| <b>OFF CHARACTERISTICS</b>   |  |                      |                     |                              |
| Collector-Emitter Sustaining Voltage (1)<br>( $I_C = 30 \text{ mAdc}$ , $I_B = 0$ )  | $BV_{CEO(sus)}$                                | 15                   | —                   | Vdc                          |
| Collector-Base Breakdown Voltage<br>( $I_C = 10 \mu\text{Adc}$ , $I_E = 0$ )   | $BV_{CBO}$                                     | 40                   | —                   | Vdc                          |
| Emitter-Base Breakdown Voltage<br>( $I_E = 10 \mu\text{Adc}$ , $I_C = 0$ )   | $BV_{EBO}$                                     | 5.0                  | —                   | Vdc                          |
| Collector Cutoff Current<br>( $V_{CB} = 20 \text{ Vdc}$ , $I_E = 0$ )<br>( $V_{CB} = 20 \text{ Vdc}$ , $I_E = 0$ , $T_A = +150^\circ\text{C}$ )  | $I_{CBO}$                                      | —                    | 0.015<br>50         | $\mu\text{Adc}$              |
| <b>ON CHARACTERISTICS</b>  |  |                      |                     |                              |
| DC Current Gain (1)<br>( $I_C = 0.5 \text{ mAdc}$ , $V_{CE} = 1.0 \text{ Vdc}$ )<br>( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 1.0 \text{ Vdc}$ )<br>( $I_C = 100 \text{ mAdc}$ , $V_{CE} = 5.0 \text{ Vdc}$ )<br>( $I_C = 150 \text{ mAdc}$ , $V_{CE} = 5.0 \text{ Vdc}$ ) | $h_{FE}$                                       | 40<br>40<br>35<br>30 | —<br>200<br>—<br>—  | —                            |
| Collector-Emitter Saturation Voltage<br>( $I_C = 10 \text{ mAdc}$ , $I_B = 1 \text{ mAdc}$ )<br>( $I_C = 50 \text{ mAdc}$ , $I_B = 5 \text{ mAdc}$ )<br>( $I_C = 100 \text{ mAdc}$ , $I_B = 10 \text{ mAdc}$ )   | $V_{CE(sat)}$                                  | —<br>—<br>—          | 0.2<br>0.35<br>0.5  | Vdc                          |
| Base-Emitter Saturation Voltage<br>( $I_C = 10 \text{ mAdc}$ , $I_B = 1 \text{ mAdc}$ )<br>( $I_C = 50 \text{ mAdc}$ , $I_B = 5 \text{ mAdc}$ )<br>( $I_C = 100 \text{ mAdc}$ , $I_B = 10 \text{ mAdc}$ )  | $V_{BE(sat)}$                                  | 0.65<br>—<br>—       | 0.85<br>0.95<br>1.1 | Vdc                          |
| <b>DYNAMIC CHARACTERISTICS</b>   |  |                      |                     |                              |
| Current-Gain-Bandwidth Product<br>( $I_C = 20 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 100 \text{ MHz}$ )  | $f_T$  | 300                  | —                   | MHz                          |
| Output Capacitance<br>( $V_{CB} = 10 \text{ Vdc}$ , $I_E = 0$ , $f = 100 \text{ kHz}$ )  | $C_{ob}$                                       | —                    | 5.0                 | pF                           |
| Input Capacitance<br>( $V_{BE} = 0.5 \text{ Vdc}$ , $I_C = 0$ , $f = 100 \text{ kHz}$ )  | $C_{ib}$                                       | —                    | 7.0                 | pF                           |
| Charge-Storage Time Constant (Figure 2)<br>( $I_C = 10 \text{ mAdc}$ , $I_{B1} = I_{B2} = 10 \text{ mAdc}$ )   | $t_s$  | —                    | 25                  | ns                           |
| Turn-On Time (Figure 1)<br>( $I_C = 10 \text{ mAdc}$ , $I_{B1} = 3 \text{ mAdc}$ , $I_{B2} = 1 \text{ mAdc}$ )   | $t_{on}$                                       | —                    | 35                  | ns                           |
| Turn-Off Time (Figure 1)<br>( $I_C = 10 \text{ mAdc}$ , $I_{B1} = 3 \text{ mAdc}$ , $I_{B2} = 1 \text{ mAdc}$ )  | $t_{off}$                                      | —                    | 75                  | ns                           |
| <b>MATCHING CHARACTERISTICS</b>  |  |                      |                     |                              |
| DC Current Gain Ratio**<br>( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 1 \text{ Vdc}$ )  | $h_{FE1}/h_{FE2}$ **                           | 0.9<br>0.8           | 1.0<br>1.0          | —                            |
| Base Voltage Differential<br>( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 1 \text{ Vdc}$ )  | $ V_{BE1} - V_{BE2} $                          | —                    | 5.0<br>10           | mVdc                         |
| Base Voltage Differential Gradient<br>( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 1 \text{ Vdc}$ , $T_A = -55$ to $+125^\circ\text{C}$ )   | $\frac{\Delta(V_{BE1} - V_{BE2})}{\Delta T_A}$ | —                    | 10<br>20            | $\mu\text{V}/^\circ\text{C}$ |

(1) Pulse Test: Pulse Width = 300  $\mu\text{s}$ ; Duty Cycle = 2%\*\*The lowest  $h_{FE}$  reading is taken as  $h_{FE1}$  for this test.